

μPD720231A

ASSP (USB3.0 to SATA3 BRIDGE CONTROLLER)



R19DS0077EJ0100

Rev 1.00

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1. OVERVIEW

The μPD720231A is a USB3.0 to SATA3 Bridge LSI which complies with Universal Serial Bus 3.0 (USB3.0) Specification Revision 1.0 and Serial ATA (SATA) Specification Revision 3.0. The LSI is integrated USB3.0 function controller and SATA III host controller with USB3.0 transceiver, USB2.0 transceiver and SATA III transceiver into one chip. The USB3.0 transceiver supports SuperSpeed (SS) 5 Gbps. USB2.0 transceiver supports High-Speed (HS) 480Mbps and Full-Speed (FS) 12 Mbps. And SATA III transceiver supports Gen1 1.5 Gbps / Gen2 3 Gbps / Gen3 6 Gbps.

1.1 Features

- Compliant with Universal Serial Bus 3.0 Specification Revision 1.0
 - Certified by USB Implementers Forum (TID: 340000093)
 - Supports Super/High-/Full-speed
 - Supports Mass Storage Class UASP (USB Attached SCSI Protocol)
 - Supports Mass Storage Class BOT (Bulk Only Transport)
 - Includes SCSI Command hardware accelerator
 - Supported number of stream is 32 + Task management.
- Compliant with Serial ATA Specification Revision 3.0.
 - Supports Gen1 / Gen2 / Gen3
 - Supports Host initiated power management
 - Supports multiple LUN
 - Be capable of providing full ATA-8, 48-Bit LBA support, for drives larger than 2TB.
- Supports power management
 - USB3.0 U1/U2/U3 state
 - USB2.0 Suspend/LPM
- Integrated 32-bit RISC CPU
- 10 configurable GPIOs including
 - SPI interface for serial flash ROM.
 - Two PWM interface
 - Multi voltage level support
- Clock input: 30 MHz crystal
- On-chip reset circuit to remove external power-on-reset circuit
- Integrated mask firmware into internal mask ROM to eliminate external Flash ROM
- Power supply: 5 V single power supply, using 2 internal regulators
 - On-chip 1.0 V and 3.3 V regulator
- Package: 48-pin QFN (6 x 6 mm)

1.2 Applications

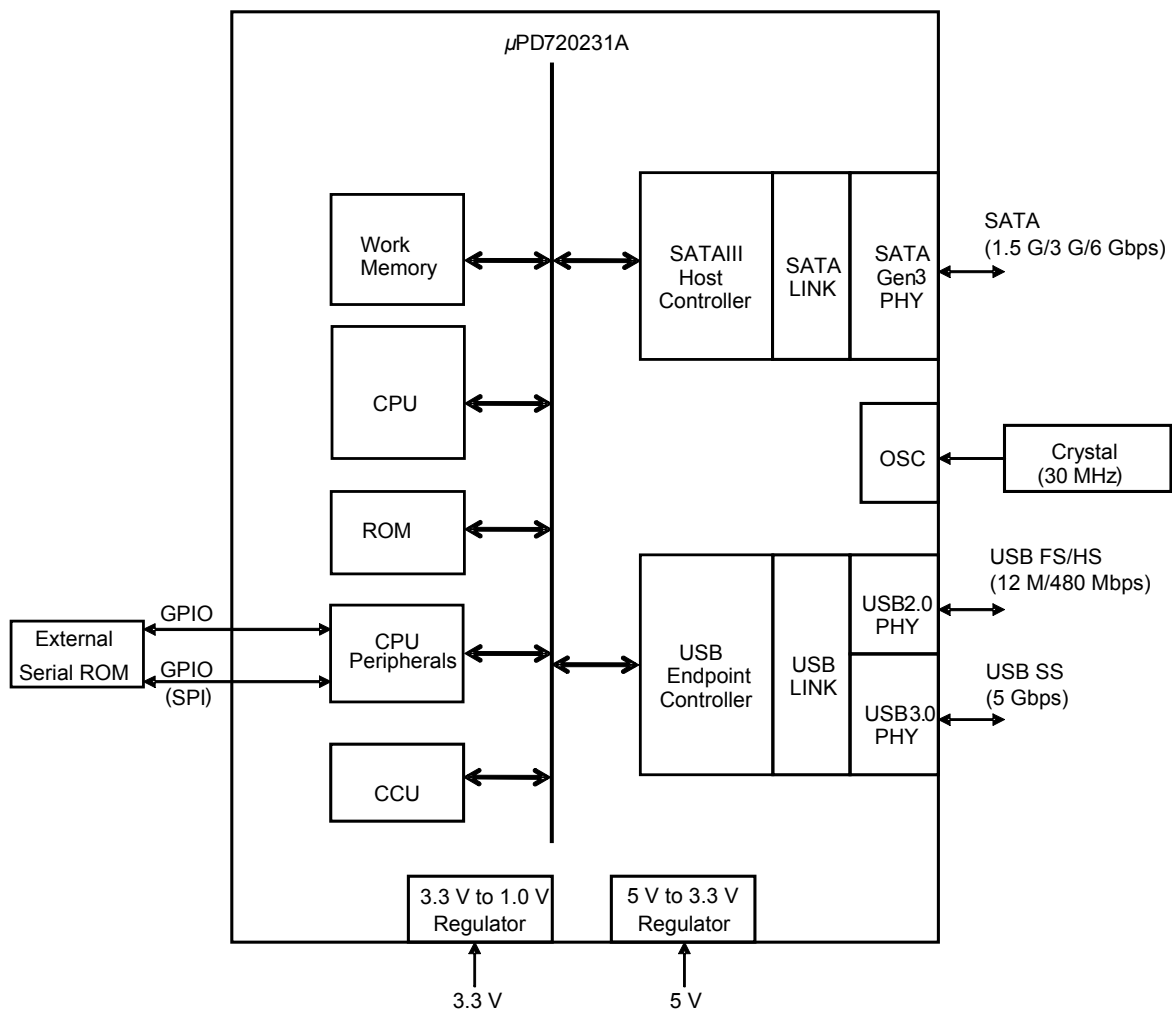
External USB hard disk/SSD, USB hard disk enclosure, optical drive, etc.

1.3 Ordering Information

Part Number	Package	Remark
μPD720231AK8-612-BAE-A	48-pin QFN (6 x 6)	Lead-free product

1.4 Block Diagram

Figure 1-1. μPD720231A Block Diagram

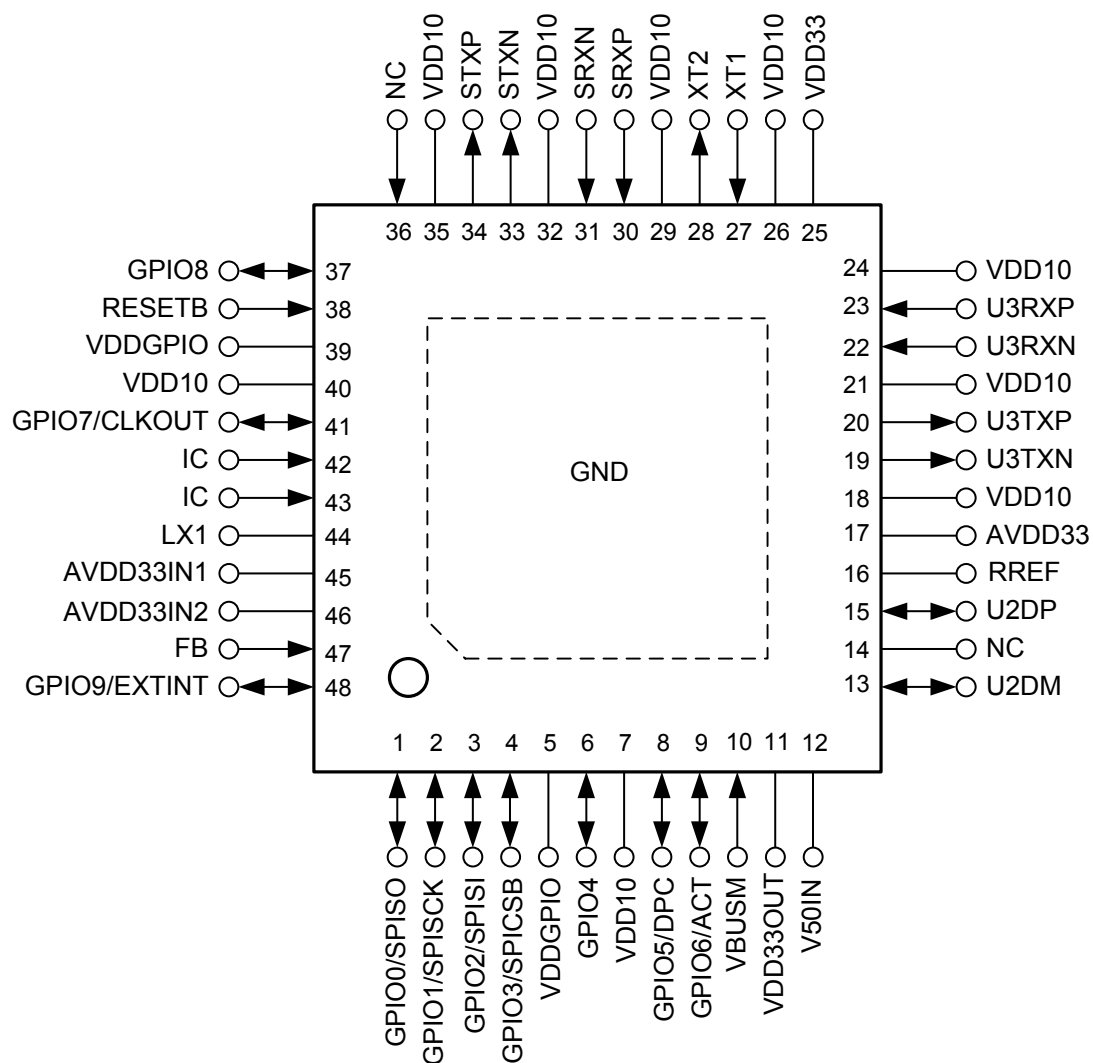


CPU	Integrated 32 bit RISC CPU.
CPU Peripherals	Includes bus controller, interrupt controller, timer, GPIO and so on.
Work RAM	Integrated Work RAM for data.
ROM	Integrated Boot ROM.
SATA III Host Controller	The SATA III host supports SATA Gen1 1.5 Gbps, Gen2 3.0 Gbps, and Gen3 6.0 Gbps. Dedicated bus realizes SuperSpeed interface between SATA III host and Direct Command Controller.
SATA LINK	Link layer translates data packets between SATA host and SATA PHY.
SATA Gen3 PHY	Integrated SATAIII Gen1 1.5 Gbps, Gen2 3.0 Gbps, and Gen3 6.0 Gbps compliance transceiver. This is controlled by SATAIII host.
USB Endpoint Controller (EPC)	Transport / Protocol layer. This block supports USB Mass Storage class USB Attached SCSI Protocol and Bulk Only Transport.
USB LINK	Link layer defined in USB specification, which maintains Link connectivity with USB host controller and hub.
USB3.0 PHY	For SuperSpeed Tx/Rx
USB2.0 PHY	For USB High/Full-speed Tx/Rx
CCU	Integrated clock controller to manage system power consumption, and system reset controller.
OSC	Internal oscillator block.
3.3 V to 1.0 V Regulator	Regulator to convert 3.3 V to 1.0 V
5 V to 3.3 V Regulator	Regulator to convert 5 V to 3.3 V

1.5 Pin Configuration

- μPD720231AK8-612-BAE-A, 48-pin QFN (6 x 6)

Figure 1-2. Pin Configuration (Top View)



2. PIN FUNCTION

This section describes each pin functions.

2.1 Power Supply and Regulator and Regulator

Table 2-1. Power Supply and Regulator

Pin Name	Pin No.	Buffer Type	Function
VDD33	25	Power	+3.3 V power supply
VDDGPIO	5, 39	Power	+3.3 V power supply for GPIOs, except for GPIO5/DPC and GPIO6/ACT.
AVDD33	17	Power	+3.3 V power supply for USB analog circuit
VDD10	7, 18, 21, 24, 26, 29, 32, 35, 40	Power	+1.0 V power supply
V50IN	12	Regulator	+5 V input for internal LDO.
VDD33OUT	11	Regulator	+3.3 V output from internal LDO.
AVDD33IN1 Note	45	Regulator	+3.3 V power supply for regulator analog circuit
AVDD33IN2 Note	46	Regulator	+3.3 V power supply for regulator analog circuit
LX1	44	Regulator	1.0 V output from the on-chip regulator
FB	47	Regulator	Feedback for regulator.
GND	Die PAD	–	Connect to ground for digital circuit

Note It is mandatory to put ceramic capacitors (22 μF is recommended) on AVDD25IN1 and AVDD25IN2. Common impedance coupling between AVDD25IN1 and AVDD25IN2 must be avoided.

2.2 Analog Signal

Table 2-2. Analog Signal

Pin Name	Pin No.	Direction	Buffer Type	Active Level	Function
RREF	16	–	USB2	–	This pin must be connected to GND via a 1.6k-ohm resistor with 1% precision.

2.3 VBUS Monitor

Table 2-3. VBUS and Regulator

Pin Name	Pin No.	Direction	Buffer Type	Active Level	Function
VBUSM	10	I	5V tolerant buffer	High	VBUS detection.

2.4 System Clock and Reset

Table 2-4. System Clock and Reset

Pin Name	Pin No.	Direction	Buffer Type	Active Level	Function
XT1	27	I	OSC	–	30 MHz oscillator input. Connect to a 30 MHz crystal.
XT2	28	O	OSC	–	30 MHz oscillator output. Connect to a 30 MHz crystal.
RESETB	38	I	3.3/2.5 V schmitt input with 50 k Ω pull-up resistor	Low	System reset

2.5 USB Interface

Table 2-5. USB Interface

Pin Name	Pin No.	Direction	Buffer Type	Active Level	Function
U3RXP	23	I	USB3	–	USB3.0 receive data D+ signal for SuperSpeed
U3RXN	22	I	USB3	–	USB3.0 receive data D- signal for SuperSpeed
U3TXP	20	O	USB3	–	USB3.0 transmit data D+ signal for SuperSpeed
U3TXN	19	O	USB3	–	USB3.0 transmit data D- signal for SuperSpeed
U2DP	15	I/O	USB2	–	USB2.0 D+ signal for High-/Full-speed
U2DM	13	I/O	USB2	–	USB2.0 D- signal for High-/Full-speed

2.6 Serial ATA Interface

Table 2-6. Serial ATA Interface

Pin Name	Pin No.	Direction	Buffer Type	Active Level	Function
SRXP	30	I	SATA III	–	Serial ATA receive data D+ signal
SRXN	31	I	SATA III	–	Serial ATA receive data D- signal
STXP	34	O	SATA III	–	Serial ATA transmit data D+ signal
STXN	33	O	SATA III	–	Serial ATA transmit data D- signal

2.7 General Purpose I/O Interface

Table 2-7. General Purpose I/O Interface

Pin Name	Pin No.	Direction	Buffer Type	During reset	After reset	Function
GPIO0/ SPISO	1	I/O	3.3/2.5 V I/O	PU	Input	General purpose I/O or SPI read data signal
GPIO1/ SPISCK	2			PU	Output	General purpose I/O or SPI clock
GPIO2/ SPISI	3			PU	Output	General purpose I/O or SPI write data signal
GPIO3/ SPICSB	4			PU	Output	General purpose I/O or SPI chip select for the external serial ROM.
GPIO4	6			Output low	Output low or HZ	General purpose I/O Default low drive. ^{Note4}
GPIO5/DPC ^{Note1}	8		5 V tolerant buffer	Input	Output high or Input ^{Note2}	General purpose I/O or SATA drive power supply control
GPIO6/ACT ^{Note1}	9			Input	Output low or Input ^{Note3}	General purpose I/O or Disk Activity LED
GPIO7/CLKOUT	41		3.3/2.5 V I/O	HZ	HZ	General purpose I/O or 30 MHz clock output
GPIO8	37			HZ	HZ	General purpose I/O
GPIO9/EXTINT	48			HZ	HZ	General purpose I/O or external interrupt such as push button input

Note 1. Except for GPIO5/DPC and GPIO6, all the other GPIOs are supplied power from VDDGPIO.
GPIO5/DPC and GPIO6 are supplied power from internal VDD33 line.

2. In active condition, GPIO5 drives high, otherwise, GPIO5 is input.

3. In active condition, GPIO6 drives low, otherwise, GPIO6 is input.

4. GPIO4 drives low in default. Other GPIO signals are open state in default.

Remark. PU: Internally pulled up, HZ: High impedance

2.8 Renesas Private Signal

Table 2-8. Renesas Private Signal

Pin Name	Pin No.	Direction	Buffer Type	Active Level	Function
IC	42, 43	I	—	—	Test signal. These pins must be connected to GND or left opened.
NC	14, 36	—	—	—	Non connection pin. This pin should be opened.

3. ELECTRICAL SPECIFICATIONS

3.1 Buffer List

Buffer type	Pin name
3.3 V input schmitt buffer with 50 k Ω pull-up resistor	RESETB
3.3 V input buffer with 50 k Ω pull-down resistor	IC
3.3 V $I_{OL} = 6$ mA bi-directional buffer (schmitt input) with 50 k Ω pull-up/down resistor	GPIO0/SPI0, GPIO1/SPI0CK, GPIO2/SPI1, GPIO3/SPI0SB, GPIO4, GPIO7/CLKOUT, GPIO8, GPIO9/EXTINT
3.3 V input buffer with 5 V tolerant	VBUSM
5 V tolerant 3.3 V $I_{OL} = 4$ mA bi-directional buffer	GPIO5/DPC, GPIO6/ACT
USB3 PHY	U3RXP, U3RXN, U3TXP, U3TXN
USB2 PHY	U2DP, U2DN, RREF
SATA III PHY	SRXP, SRXN, STXP, STXN
3.3 V Oscillator	XT1, XT2
3.3 V to 1.0 V Regulator	LX1, FB
5 V to 3.3 V Regulator	VDD33OUT

Note Uses a 5 V tolerant buffer meeting absolute maximum ratings. Note that the voltage presented at the 5 V tolerant buffer should not be higher than V_i at any given time.

3.2 Terminology

Table 3-1. Terms Used in Absolute Maximum Ratings

Parameter	Symbol	Meaning
Power supply voltage	V50IN, VDD33, AVDD33, AVDD33IN1, AVDD33IN2, VDD10	Indicates the voltage range within which damage or reduced reliability will not result when power is applied to a VDD pin.
Input voltage	V_i	Indicates voltage range within which damage or reduced reliability will not result when power is applied to an input pin.
Output voltage	V_o	Indicates voltage range within which damage or reduced reliability will not result when power is applied to an output pin.
Output current	I_o	Indicates absolute tolerance values for DC current to prevent damage or reduced reliability when current flows out of or into output pin.
Storage temperature	T_{stg}	Indicates the element temperature range within which damage or reduced reliability will not result while no voltage or current is applied to the device.

Table 3-2. Terms Used in Recommended Operating Range

Parameter	Symbol	Meaning
Power supply voltage	V50IN, VDD33, AVDD33, AVDD33IN1, AVDD33IN2, VDD10	Indicates the voltage range for normal logic operations occur when GND = 0 V.
High-level input voltage	V_{IH}	Indicates the voltage, which is applied to the input pins of the device, is the voltage indicates that the high level states for normal operation of the input buffer. * If a voltage that is equal to or greater than the "Min." value is applied, the input voltage is guaranteed as high level voltage.
Low-level input voltage	V_{IL}	Indicates the voltage, which is applied to the input pins of the device, is the voltage indicates that the low level states for normal operation of the input buffer. * If a voltage that is equal to or lesser than the "Max." value is applied, the input voltage is guaranteed as low level voltage.
Hysteresis voltage	V_H	Indicates the differential between the positive trigger voltage and the negative trigger voltage.
Input rise time	T_{ri}	Indicates the limit value for the time period when an input voltage applied to the input pins of the device rises from 10 % to 90 %.
Input fall time	T_{fi}	Indicates the limit value for the time period when an input voltage applied to the input pins of the device falls from 90 % to 10 %.
Operating temperature	T_A	Indicates the ambient temperature range for normal logic operations.

Table 3-3. Term Used in DC Characteristics

Parameter	Symbol	Meaning
Off-state output leakage current	I_{oz}	Indicates the current that flows from the power supply pins when the rated power supply voltage is applied when a 3-state output has high impedance.
Input leakage current	I_i	Indicates the current that flows when the input voltage is supplied to the input pin.
High-level output voltage	V_{OL}	Indicates the output voltage at low level and when the output pin is open.
Low-level output voltage	V_{OH}	Indicates the output voltage at high level and when the output pin is open.

3.3 Absolute Maximum Ratings

Table 3-4. Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Units
Power supply voltage	V50IN		−0.5 to +5.5	V
	VDD33 VDDGPIO AVDD33 AVDD33IN1 AVDD33IN2		−0.5 to +4.6	V
	VDD10		−0.5 to +1.4	V
Input voltage, 3.3 V buffer	V_i	$V_i < VDD33/VDDGPIO + 0.5\text{ V}$	−0.5 to +4.6	V
Input voltage, 5 V tolerant buffer	V_i	$V50IN > 4.0\text{ V}$	−0.5 to +6.0	V
Output voltage, 3.3 V buffer	V_o	$V_o < VDD33/VDDGPIO + 0.5\text{ V}$	−0.5 to +4.6	V
Output voltage, 5 V tolerant buffer	V_o	$V50IN > 4.0\text{ V}$	−0.5 to +6.0	V
USB3/SATA differential signals	V_i/V_o	$V_i/V_o < VDD10 + 0.5\text{ V}$	−0.5 to +1.4	V
Output current	I_o	4 mA type (5 V tolerant buffer)	10.35	mA
		6 mA type (3.3 V buffer)	16.9	mA
Storage temperature	T_{stg}		−65 to +125	°C

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameters. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded. The ratings and conditions indicated for DC characteristics and AC characteristics represent the quality assurance range during normal operation.

3.4 Recommended Operating Ranges

Table 3-5. Recommended Operating Ranges

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units
Operating voltage	V50IN		4.0	5.0	5.25	V
	VDD33 ^{Note} AVDD33 ^{Note} AVDD33IN1 ^{Note} AVDD33IN2 ^{Note}		3.0	3.3	3.6	V
	VDDGPIO ^{Note}	3.3 V operation	3.0	3.3	3.6	V
		2.5 V operation	2.25	2.5	2.75	V
	VDD10		0.95	1.0	1.05	V
High-level input voltage	V_{IH}	Normal buffer 3.3 V	2		VDD33+0.3	V
		Normal buffer 2.5 V	TBD		TBD	
Low-level input voltage	V_{IL}	Normal buffer 3.3 V	-0.3		0.8	V
		Normal buffer 2.5 V	TBD		TBD	
Positive trigger voltage	V_P	Schmitt buffer 3.3 V	0.9		2.1	V
		Schmitt buffer 2.5 V	TBD		TBD	
Negative trigger voltage	V_N	Schmitt buffer 3.3 V	0.7		1.9	V
		Schmitt buffer 2.5 V	TBD		TBD	
Hysteresis voltage	V_H	Schmitt buffer 3.3 V	0.2		1.4	V
		Schmitt buffer 2.5 V	TBD		TBD	
Input rise time	T_{ri}	Normal buffer	0		200	ns
		Schmitt buffer	0		1	ms
Input fall time	T_{fi}	Normal buffer	0		200	ns
		Schmitt buffer	0		1	ms
Operating ambient temperature	T_A		0		+85	°C

Note VDD33, AVDD33, AVDD33IN1, AVDD33IN2 and VDDGPIO must turn on/off at the same time and should be stable within 100 ms from the fastest rising edge of power sources.

3.5 DC Characteristics (VDD33 = 3.3 V ± 10%, T_A = 0 to +85 °C)

Table 3-6. DC Characteristics

Parameter	Symbol	Condition	Min.	Max.	Units
Off-state output current	I _{oz}	V _I = VDD33/VDDGPIO or GND		±8	μA
Low-level output current	I _{OL}	V _{OL} = 0.4 V	6 mA type	6	mA
			4 mA type	4	mA
High-level output current	I _{OH}	V _{OH} = 2.4 V	6 mA type	-6	mA
			4 mA type	-4	mA
Input leakage current	I _I	V _I = VDD33/VDDGPIO or GND	Normal input		±5 μA
		V _I = GND	With pull-up resistor (50 kΩ)	24	78 μA
		V _I = VDD33/VDDGPIO	With pull-down resistor (50 kΩ)	24	78 μA

Remark For pins with internal pull-up, the internal pull-up assures that when the pin is open, the pin voltage will be greater than the V_{IH} level.

Table 3-7. USB Interface Block

(1/2)

Parameter	Symbol	Conditions	Min.	Max.	Unit
Output pin impedance	Z _{HSDRV}		40.5	49.5	Ω
Termination voltage for upstream facing port pull-up (RPU)	V _{TERM}		3.0	3.6	V
Input Levels for Full-speed:					
High-level input voltage (drive)	V _{IH}		2.0		V
High-level input voltage (floating)	V _{IHZ}		2.7	3.6	V
Low-level input voltage	V _{IL}			0.8	V
Differential input sensitivity	V _{DI}	(D+) - (D-)	0.2		V
Differential common mode range	V _{CM}	Includes V _{DI} range	0.8	2.5	V
Output Levels for Full-speed:					
High-level output voltage	V _{OH}	R _L of 14.25 kΩ to GND	2.8	3.6	V
Low-level output voltage	V _{OL}	R _L of 1.425 kΩ to 3.6 V	0.0	0.3	V
SE1	V _{OSE1}		0.8		V
Output signal crossover point voltage	V _{CRS}		1.3	2.0	V
Input Levels for High-speed:					
High-speed squelch detection threshold (differential signal)	V _{HSSQ}		100	150	mV
High-speed data signaling common mode voltage range	V _{HSCM}		-50	+500	mV
High-speed differential input signaling level	See Figure 3-2.				

Parameter	Symbol	Conditions	Min.	Max.	Unit
Output Levels for High-speed:					
High-speed idle state	V _{HSOI}		−10	+10	mV
High-speed data signaling high	V _{HSOH}		360	440	mV
High-speed data signaling low	V _{HSOL}		−10	+10	mV
Chirp J level (differential signal)	V _{CHIRPJ}		700	1100	mV
Chirp K level (differential signal)	V _{CHIRPK}		−900	−500	mV

Figure 3-1. Differential Input Sensitivity Range for Full-speed

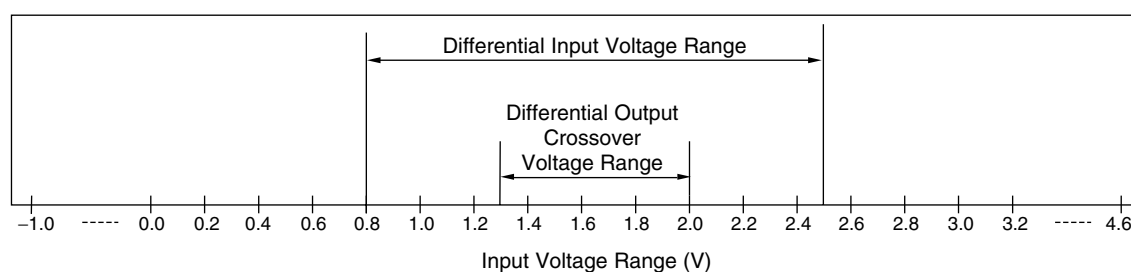


Figure 3-2. Receiver Sensitivity for Transceiver at U2DP/U2DM

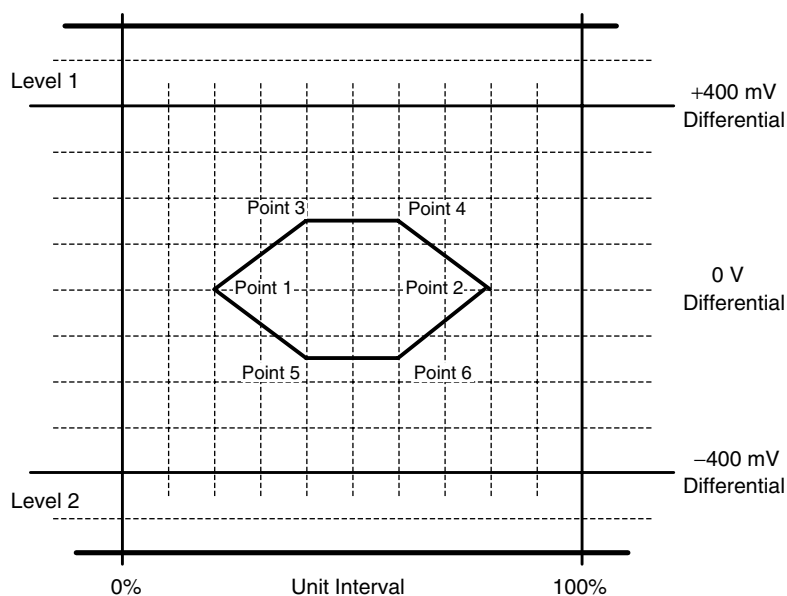
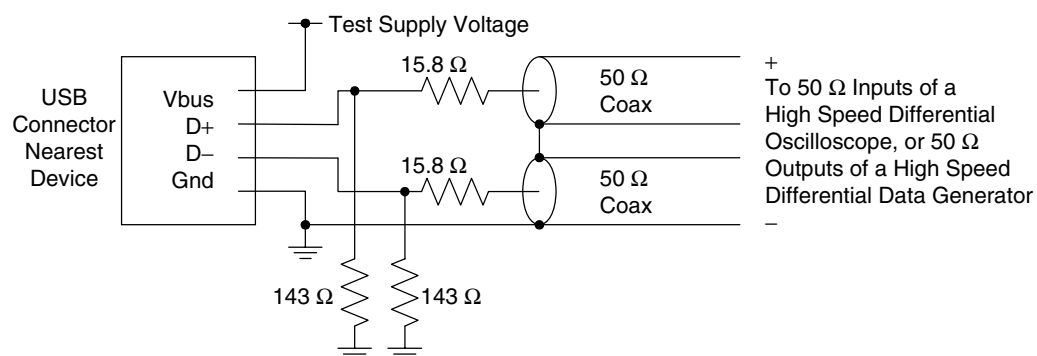


Figure 3-3. Receiver Measurement Fixtures



3.6 Pin Capacitance

Table 3-8. Pin Capacitance

Parameter	Symbol	Condition	Min.	Max.	Units
GPIO pin capacitance	C_{GPIO}			5	pF

3.7 AC Characteristics (VDD33 = 3.3 V $\pm$ 10%, T_A = 0 to +85 °C)

3.7.1 System Clock

Table 3-9. System Clock (XT1/XT2) Ratings

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units
Clock frequency	F _{CLK}	Crystal	−100 ppm	30	+100 ppm	MHz
Clock duty cycle	T _{DUTY}		40	50	60	%

Remark Required accuracy of crystal or oscillator block includes initial frequency accuracy, the spread of Crystal capacitor loading, supply voltage, temperature and aging, etc.

3.7.2 System Reset

Table 3-10. System Reset Timings

Parameter	Symbol	Condition	Min.	Max.	Units
Reset active time	T _{RESETB}		1		μs

Remark RESETB shall be de-asserted after all power sources (excluding VBUS) and the system clock become stable.

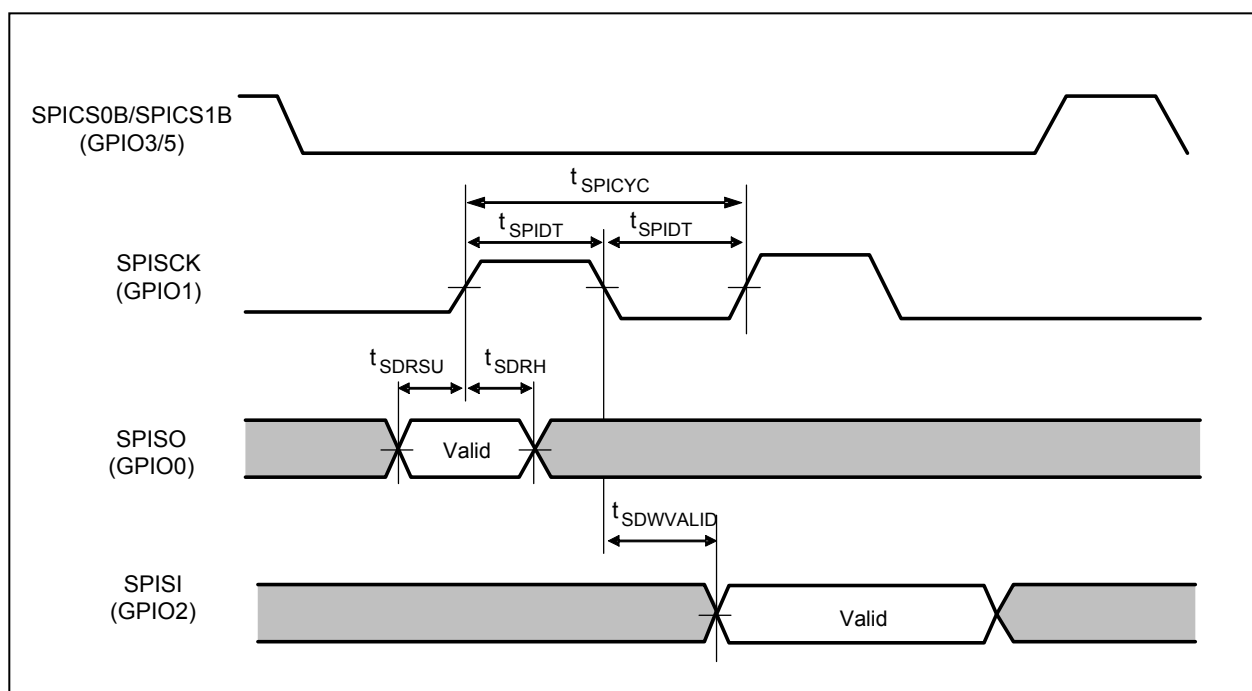
3.7.3 GPIO

(1) SPI Type Serial Flash ROM interface

Table 3-11. SPI Type Serial Flash ROM Interface (SPI Mode 0)

Parameter	Symbol	Min.	Typ.	Max.	Units
SPISCK clock frequency	t _{SPICYC}	1.5		15	MHz
SPISCK clock duty	t _{SPIDT}		50		%
SPISO setup time to SPISCK rising edge	t _{SDRSU}	2			ns
SPISO hold time to SPISCK rising edge	t _{SDRH}	3			ns
SPISI validate time from SPISCK falling edge	t _{SDWVALID}			1	ns

Figure 3-4. SPI Type Serial Flash ROM Interface



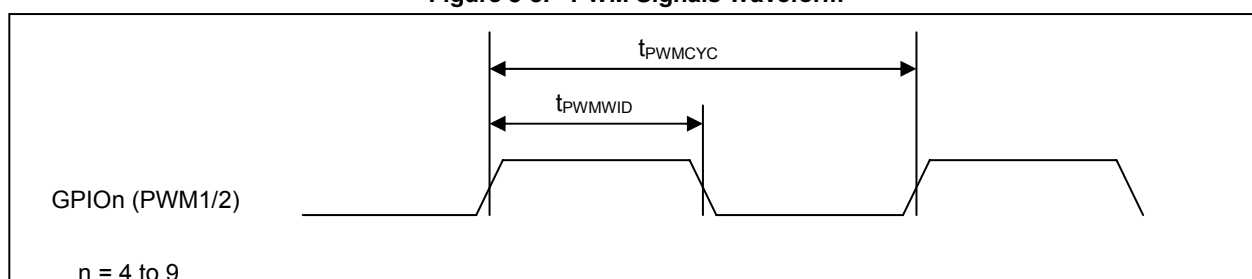
(2) Pulse Width Modulation (PWM) signal

Table 3-12. PWM Signals

Parameter	Symbol	Min.	Max.	Units
PWM 1/2 cycle time	t_{PWMCYC}	0.067	143,165,576.500	μs
PWM 1/2 high level width	t_{PWMWID}	0.033	143,165,576.467	μs

Note t_{PWMCYC} and t_{PWMWID} are controlled by 33.3 ns step.

Figure 3-5. PWM Signals Waveform



3.7.4 SATA Interface – Differential Transmitter (TX) Specifications

(Refer to Serial ATA Specification Revision 3.0 for more information)

Table 3-13. Differential Transmitter Specification (1/2)

Parameters	Symbol	Limit	SATA 3.0 Spec			Units
			Gen1i	Gen2i	Gen3i	
Sequencing Transient Voltage LL	V_{trans}	Min	–	–	–1.2	V
		Max	–	–	1.2	
TX Pair Differential Impedance	Z_{diffTX}	Min	86	–	–	Ω
		Max	115	–	–	
TX Single-Ended Impedance	Z_{s-eTX}	Min	40	–	–	Ω
TX Differential Mode Return Loss (all values Min)	$RL_{DD11,TX}$	75 MHz- 150 MHz	14	–	–	dB
		150 MHz- 300 MHz	8	14	–	
		300 MHz- 600 MHz	6	8	–	
		600 MHz- 1.2 GHz	6	6	–	
		1.2 GHz- 2.4 GHz	3	6	–	
		2.4 GHz- 3.0 GHz	1	3	–	
		3.0 GHz- 5.0 GHz	–	1	–	
TX Differential Mode Return Loss Start for slope	$RL_{DD11,TX}$	Min at 300 MHz	–	–	14	dB
Slope of TX Differential Mode Return Loss		Nom	–	–	–13	dB/dec
TX Differential Mode Return Loss Max Frequency		Max	–	–	3	GHz
TX Common Mode Return Loss (all values Min)	$RL_{CC11,TX}$	150 MHz- 300 MHz	–	8	–	dB
		300 MHz- 600 MHz	–	5	–	
		600 MHz- 1.2 GHz	–	2	–	
		1.2 GHz- 2.4 GHz	–	1	–	
		2.4 GHz- 3.0 GHz	–	1	–	
		3.0 GHz- 5.0 GHz	–	1	–	

Table 3-13. Differential Transmitter Specification (2/2)

Parameters	Symbol	Limit	SATA 3.0 Spec			Units
			Gen1i	Gen2i	Gen3i	
TX Impedance Balance (all values Min)	RL _{DC11,TX}	150 MHz- 300 MHz	—	30	30	dB
		300 MHz- 600 MHz	—	20	30	
		600 MHz- 1.2 GHz	—	10	20	
		1.2 GHz- 2.4 GHz	—	10	10	
		2.4 GHz- 3.0 GHz	—	4	10	
		3.0 GHz- 5.0 GHz	—	4	4	
		5.0 GHz- 6.5 GHz	—	—	4	

3.7.5 SATA Interface – Differential Receiver (RX) Specifications

(Refer to Serial ATA Specification Revision 3.0 for more information)

Table 3-14. Differential Receiver Specification (1/2)

Parameters	Symbol	Limit	SATA 3.0 Spec			Units
			Gen1i	Gen2i	Gen3i	
RX Pair Differential Impedance	Z _{diffRX}	Min	85	—	—	Ω
		Max	115	—	—	
RX Single-Ended Impedance	Z _{s-eRX}	Min	40	—	—	Ω
RX Differential Mode Return Loss (all values Min)	RL _{DD11,RX}	75 MHz- 150 MHz	18	—	—	dB
		150 MHz- 300 MHz	14	18	—	
		300 MHz- 600 MHz	10	14	—	
		600 MHz- 1.2 GHz	8	10	—	
		1.2 GHz- 2.4 GHz	3	8	—	
		2.4 GHz- 3.0 GHz	1	3	—	
		3.0 GHz- 5.0 GHz	—	1	—	

Table3-14. Differential Receiver Specification (2/2)

Parameters	Symbol	Limit	SATA 3.0 Spec			Units
			Gen1i	Gen2i	Gen3i	
RX Differential Mode Return Loss	RL _{DD11,RX}	Min at 300 MHz	—	—	18	dB
Slope of RX Differential Mode Return Loss		Nom	—	—	−13	dB/dec
RX Differential Mode Return Loss Max Frequency		Max	—	—	6	GHz
RX Common Mode Return Loss (all values Min)	RL _{CC11,RX}	150 MHz-300 MHz	—	5	—	dB
		300 MHz-600 MHz	—	5	—	
		600 MHz-1.2 GHz	—	2	—	
		1.2 GHz-2.4 GHz	—	1	—	
		2.4 GHz-3.0 GHz	—	1	—	
		3.0 GHz-5.0 GHz	—	1	—	
RX Impedance Balance (all values Min)	RL _{DC11,RX}	150 MHz-300 MHz	—	30	30	dB
		300 MHz-600 MHz	—	30	30	
		600 MHz-1.2 GHz	—	20	20	
		1.2 GHz-2.4 GHz	—	10	10	
		2.4 GHz-3.0 GHz	—	4	4	
		3.0 GHz-5.0 GHz	—	4	4	
		5.0 GHz-6.5 GHz	—	4	4	

3.7.6 USB3.0 SuperSpeed Interface – Differential Transmitter (TX) Specifications

(Refer to Universal Serial Bus 3.0 Specification Revision 1.0 for more information)

Table 3-15. Transmitter Normative Electrical Parameters

Parameter	Symbol	Min	Max	Units
Unit Interval	UI	199.94	200.06	ps
Differential p-p Tx voltage swing	$V_{TX-DIFF-PP}$	0.8	1.2	V
Tx de-emphasis	$V_{TX-DE-RATIO}$	3.0	4.0	dB
DC differential impedance	$R_{TX-DIFF-DC}$	72	120	Ω
The amount of voltage change allowed during Receiver Detection	$V_{TX-RCV-DETECT}$		0.6	V
AC Coupling Capacitor	$C_{AC-COUPLING}$	75	200	nF
Maximum slew rate	$t_{CDR-SLEW-MAX}$		10	ms/s

Table 3-16. Transmitter Informative Electrical Parameters

Parameter	Symbol	Min	Max	Units
Deterministic min pulse	$t_{MIN-PULSE-DJ}$	0.96		UI
Tx min pulse	$t_{MIN-PULSE-TJ}$	0.90		UI
Transmitter Eye	t_{TX-EYE}	0.625		UI
Tx deterministic jitter	$t_{TX-DJ-DD}$		0.205	UI
Tx input capacitance for return loss	$C_{TX-PARASITIC}$		1.25	pf
Transmitter DC common mode impedance	R_{TX-DC}	18	30	Ω
Transmitter short-circuit current limit	$I_{TX-SHORT}$		60	mA
Transmitter DC common-mode voltage	$V_{TX-DC-CM}$	0	2.2	V
Tx AC common mode voltage	$V_{TX-CM-AC-PP-ACTIVE}$		100	mVp-p
Absolute DC Common Mode Voltage between U1 and U0	$V_{TX-CM-DC-ACTIVE-IDLE-DELTA}$		200	mV
Electrical Idle Differential Peak- Peak Output voltage	$V_{TX-IDLE-DIFF-AC-PP}$	0	10	mV
DC Electrical Idle Differential Output Voltage	$V_{TX-IDLE-DIFF-DC}$	0	10	mV

3.7.7 USB3.0 SuperSpeed Interface – Differential Receiver (RX) Specifications

(Refer to Universal Serial Bus 3.0 Specification Revision 1.0 for more information)

Table 3-17. Receiver Normative Electrical Parameters

Parameter	Symbol	Min	Max	Units
Unit Interval	UI	199.94	200.06	ps
Receiver DC common mode impedance	R_{RX-DC}	18	30	Ω
DC differential impedance	$R_{RX-DIFF-DC}$	72	120	Ω
DC Input CM Input Impedance for $V > 0$ during Reset of Power down	$Z_{RX-HIGH-IMP-DC-POS}$	25k		Ω
LFPS Detect Threshold	$V_{RX-LFPS-DET-DIFF-p-p}$	100	300	mV

Table 3-18. Receiver Informative Electrical Parameters

Parameter	Symbol	Min	Max	Units
Differential Rx peak-to-peak voltage	$V_{RX-DIFF-PP-POST-EQ}$	30		mV
Max Rx inherent timing error	T_{RX-TJ}		0.45	UI
Max Rx inherent deterministic timing error	$T_{RX-DJ-DD}$		0.285	UI
Rx input capacitance for return loss	$C_{RX-PARASITIC}$		1.1	pF
Rx AC common mode voltage	$V_{RX-CM-AC-P}$		150	mVPeak
Rx AC common mode voltage during the U1 to U0 transition	$V_{RX-CM-DC-ACTIVE-IDLE-DELTA-P}$		200	mVPeak

3.7.8 USB2.0 Interface

(Refer to Universal Serial Bus Specification Revision 2.0 for more information)

Table 3-19. Full-speed Source Electrical Characteristics

Parameter	Symbol	Conditions	Min.	Max.	Unit
Rise time (10 to 90%)	t_{FR}	$C_L = 50 \text{ pF}$	4	20	ns
Fall time (90 to 10%)	t_{FF}	$C_L = 50 \text{ pF}$	4	20	ns
Differential rise and fall time matching	t_{FRFM}	(t_{FR}/t_{FF})	90	111.11	%
Full-speed data rate	$t_{FDRATHS}$	Average bit rate	11.9940	12.0060	Mbps
Frame interval	t_{FRAME}		0.9995	1.0005	ms
Consecutive frame interval jitter	t_{RFI}	No clock adjustment		42	ns
Source jitter total (including frequency tolerance):					
To next transition	t_{DJ1}		-3.5	+3.5	ns
For paired transitions	t_{DJ2}		-4.0	+4.0	ns
Source jitter for differential transition to SE0 transition	t_{FDEOP}		-2	+5	ns
Receiver jitter:					
To next transition	t_{JR1}		-18.5	+18.5	ns
For paired transitions	t_{JR2}		-9	+9	ns
Source SE0 interval of EOP	t_{FEOPT}		160	175	ns
Receiver SE0 interval of EOP	t_{FEOPR}		82		ns
Width of SE0 interval during differential transition	t_{FST}			14	ns

Table 3-20. High-speed Source Electrical Characteristics

Parameter	Symbol	Conditions	Min.	Max.	Unit
Rise time (10 to 90%)	t_{HSR}		500		ps
Fall time (90 to 10%)	t_{HSF}		500		ps
Driver waveform	See Figure 3-6.				
High-speed data rate	t_{HSDRAT}		479.760	480.240	Mbps
Microframe interval	t_{HSFRAM}		124.9375	125.0625	μs
Consecutive microframe interval difference	t_{HSRFI}			4 high-speed	Bit times
Data source jitter	See Figure 3-6.				
Receiver jitter tolerance	See Figure 3-2.				

Table 3-21. Device Event Timings

Parameter	Symbol	Conditions	Min.	Max.	Unit
Time from internal power good to device pulling D+ beyond V _{IHZ} (min.) (signaling attached)	t _{SIGATT}			100	ms
Debounce interval provided by USB system software after attach	t _{ATTDDB}			100	ms
Inter-packet delay for full-speed	t _{IPD}		2		Bit times
Inter-packet delay for device response w/detachable cable for full-speed	t _{RSPDP1}			6.5	Bit times
Time for which a suspended high-speed capable device must see a continuous SE0 before beginning the high-speed detection handshake	t _{FILTSE0}		2.5		μs
Time a high-speed capable device operating in non-suspended full-speed must wait after start of SE0 before beginning the high-speed detection handshake	t _{WTRSTFS}		2.5	3000	μs
Time a high-speed capable device operating in high-speed must wait after start of SE0 before reverting to full-speed	t _{WTREV}		3.0	3.125	ms
Time a device must wait after reverting to full-speed before sampling the bus state for SE0 and beginning the high-speed detection handshake	t _{WTRSTHS}		100	875	μs
Minimum duration of a Chirp K from a high-speed capable device within the reset protocol	t _{UCH}		1.0		ms
Time after start of SE0 by which a high-speed capable device is required to have completed its Chirp K within the reset protocol	t _{UCHEND}			7.0	ms
Time between detection of downstream chirp and entering high-speed state	t _{WTHS}			500	μs
Time after end of upstream chirp at which device reverts to fullspeed default state if no downstream chirp is detected	t _{WTFS}		1.0	2.5	ms

Figure 3-6. Transmit Waveform for Transceiver at U2DP/U2DM

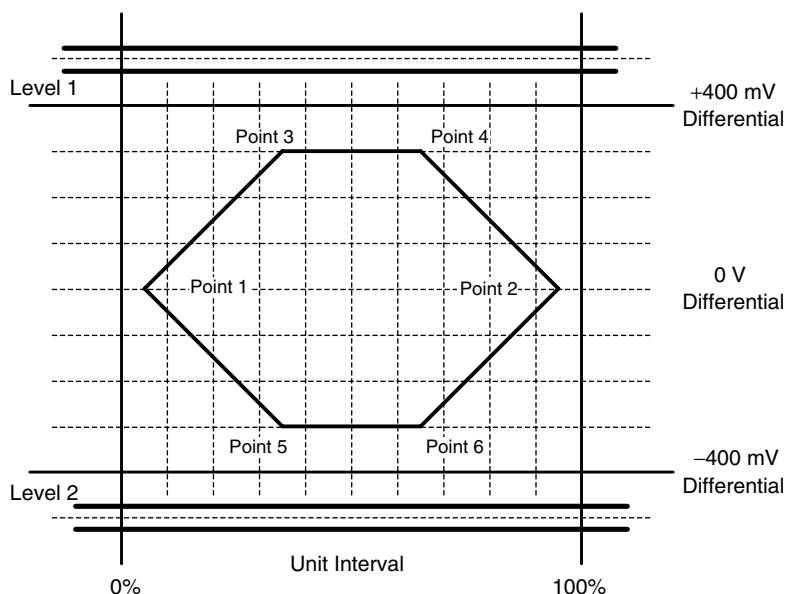


Figure 3-7. Transmitter Measurement Fixtures

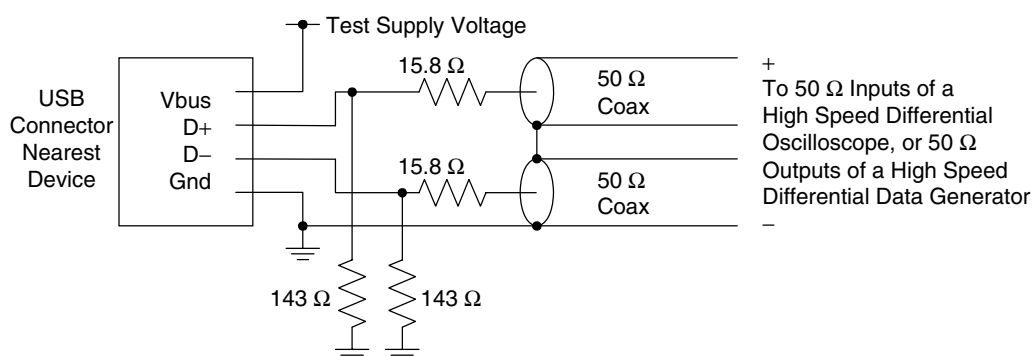


Figure 3-8. USB Differential Data Jitter for Full-speed

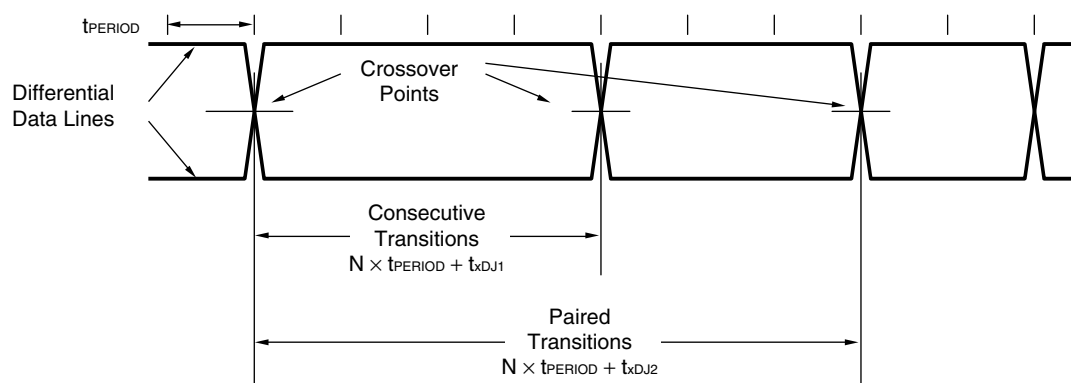


Figure 3-9. USB Differential-to-EOP Transition Skew and EOP Width for Full-speed

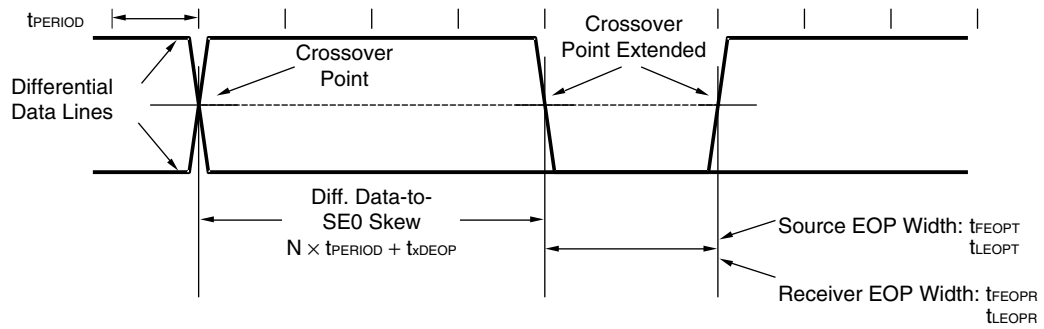
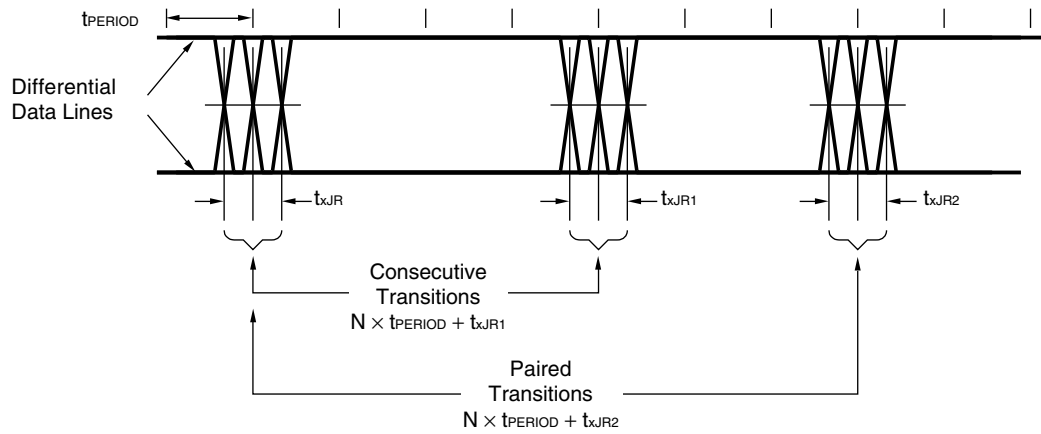


Figure 3-10. USB Receiver Jitter Tolerance for Full-speed



3.8 Power Consumption

3.8.1 Power consumption with on-chip switching regulator

Table 3-22. Power Consumption in SuperSpeed Operation Mode

Symbol	Condition	V50IN (Bus-power setting)	V50IN (Self-power setting)	Units
$P_{SS_U0Unconf}$	USB Unconfigured state with SATA Slumber	63	63	mA
P_{SS_U0DT}	Data transfer at SuperSpeed with SATA Gen3	126	126	mA
	with SATA Gen2	116	116	mA
	with SATA Gen1	108	108	mA
P_{SS_U3}	USB3.0 U3 state	2.0	5.6	mA

Typical condition: $T_A = 25\text{ }^{\circ}\text{C}$, $V50IN = 5.0\text{ V}$

Note 1. On-chip switching regulator is cascaded to on-chip LDO.

Table 3-23. Power Consumption in High-speed Operation Mode

Symbol	Condition	V50IN (Bus-power setting)	V50IN (Self-power setting)	Units
$P_{HS_L0Unconf}$	USB Unconfigured state with SATA Slumber	66	66	mA
P_{HS_L0DT}	Data transfer at High-Speed with SATA Gen1	122	122	mA
P_{HS_U3}	USB2.0 L2	2.2	5.8	mA

Typical condition: $T_A = 25\text{ }^{\circ}\text{C}$, $V50IN = 5.0\text{ V}$

Note 1. On-chip switching regulator is cascaded to on-chip LDO.

3.8.2 Power consumption without on-chip switching regulator

Table 3-24. Power Consumption in SuperSpeed Operation Mode

Symbol	Condition	Bus-power setting		Self-power setting		Units
		VDD10	V50IN	VDD10	V50IN	
$P_{SS_U0Unconf}$	USB Unconfigured state with SATA Slumber	140	14	140	14	mA
P_{SS_U0DT}	Data transfer at SuperSpeed with SATA Gen3	270	24	270	24	mA
	with SATA Gen2	245	24	245	24	mA
	with SATA Gen1	228	24	228	24	mA
P_{SS_U3}	USB3.0 U3 state	1.2	0.9	1.7	2.5	mA

Typical condition: $T_A = 25\text{ }^{\circ}\text{C}$, VDD10=1.0 V, V50IN = 5.0 V

Note 1. Power consumption of 3.3 V(VDD33, AVDD33, AVDD33IN1, AVDD33IN2) is included in V50IN.

Table 3-25. Power Consumption in High-speed Operation Mode

Symbol	Condition	Bus-power setting		Self-power setting		Units
		VDD10	V50IN	VDD10	V50IN	
$P_{HS_L0Unconf}$	USB Unconfigured state with SATA Slumber	62	42	62	42	mA
P_{HS_L0DT}	Data transfer at High-Speed with SATA Gen1	150	68	150	68	mA
P_{HS_L2}	USB2.0 L2 (Suspend) state	1.2	1.1	1.7	2.6	mA

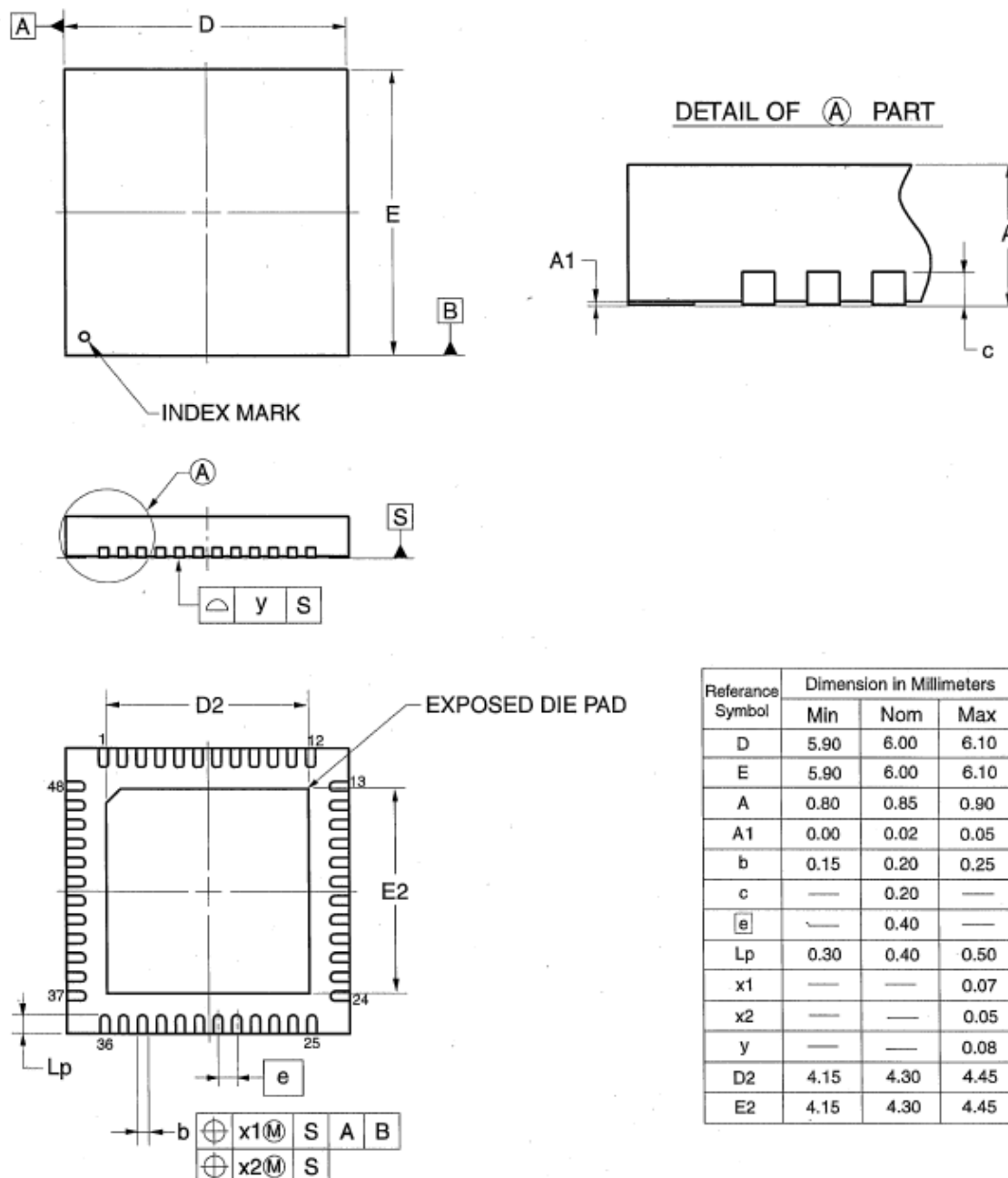
Typical condition: $T_A = 25\text{ }^{\circ}\text{C}$, VDD10 = 1.0 V, V50IN = 5.0 V

Note 1. Power consumption of 3.3 V(VDD33, AVDD33, AVDD33IN1, AVDD33IN2) is included in V50IN.

4. PACKAGE DRAWINGS

- μPD720231AK8-612-BAE-A

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-HVQFN48-6x6-0.40	PVQN0048LF-A	T48K8-40A-BAE	0.1



5. RECOMMENDED SOLDERING CONDITIONS

The μPD720231A should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, contact a Renesas Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (<http://www.renesas.com/prod/package/manual/>)

- μPD720231AK8-612-BAE-A : 48-pin QFN (6x6)

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Peak package's surface temperature: 260 °C, Reflow time: 60 seconds or less (220 °C or higher), Maximum allowable number of reflow processes: 3, Exposure limit ^{Note} : 7 days (10 to 72 hours pre-backing is required at 125C° afterwards), Flux: Rosin flux with low chlorine (0.2 Wt% or below) recommended. <Caution> Non-heat-resistant trays, such as magazine and taping trays, cannot be baked before unpacking.	IR60-107-3

Note The Maximum number of days during which the product can be stored at a temperature of 25 °C and a relative humidity of 65 % or less after dry-pack package is opened.

REVISION HISTORY	μ PD720231A Data Sheet
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Rev.	Date	Description	
		Page	Summary
0.01	Mar 15, 2013	–	First Edition issued
0.02	Apr 10, 2013	P7	Added GPIO signal state during reset and after reset.
		P8	Corrected buffer type of GPIO pins.
1.00	Jul 29, 2013	–	Document promoted from Preliminary Data to full Data.

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